Transistors

Digital transistors (built-in resistors) DTB123EK / DTB123ES

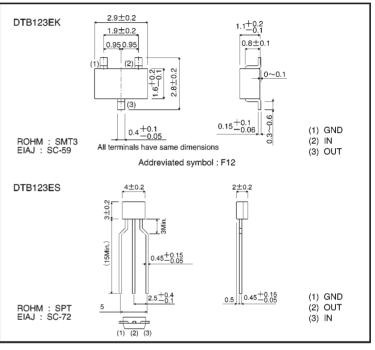
Features

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- The bias resistors consist of thinfilm resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- Only the on/off conditions need to be set for operation, making device design easy.

Structure

PNP digital transistor (Built-in resistor type)



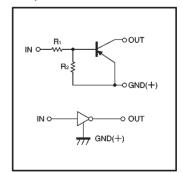


• Absolute maximum ratings (Ta = 25° C)

Parameter	Symbol	Limits(D	Unit		
Falameter	Symbol	К	S	Unit	
Supply voltage	Vcc	-50		V	
Input voltage	Vin	-1	V		
		-1			
Output current	lc	-500		mA	
Power dissipation	Pd	200	300	mW	
Junction temperature	Tj	150		Ĵ	
Storage temperature	Tstg	-55~+150		°C	

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Equivalent circuit



•Electrical characteristics (Ta = 25° C)

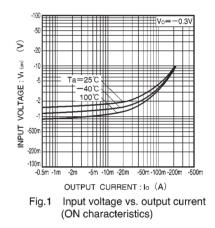
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Input voltage	VI(off)	_	-	-0.5		$V_{CC} = -5V$, $I_{O} = -100 \mu A$	
	VI(on)	-3	-	_	V	Vo=-0.3V, Io=-20mA	
Output voltage	V _{O(on)}	—	_	-0.3	V	lo/l=-50mA/-2.5mA	
Input current	h	—	_	-3.8	mA	Vi=-5V	
Output current	IO(off)	—	—	-0.5	μA	$V_{CC} = -50V, V_I = 0V$	
DC current gain	Gi	39	-	_	—	$V_0 = -5V$, $I_0 = -50mA$	
Input resistance	Rı	1.54	2.2	2.86	kΩ	_	
Resistance ratio	R2/R1	0.8	1	1.2	_	_	
Transition frequency	f⊤	—	200	_	MHz	Vce=-10V, Ie=5mA, f=100MHz *	

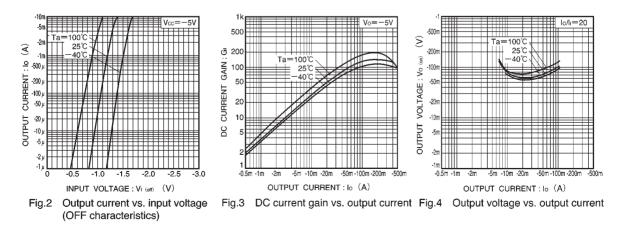
* Transition frequency of the device

Packaging specifications

	Package	SMT3	SPT
	Packaging type	Taping	Taping
	Code	T146	TP
Part No.	Basic ordering unit (pieces)	3000	5000
DTB123EK		0	_
DTB123ES		—	0

Electrical characteristic curves





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